

**WEST**[Help](#)[Logout](#)[Interrupt](#)[Main Menu](#)[Search Form](#)[Posting Counts](#)[Show S Numbers](#)[Edit S Numbers](#)[Preferences](#)[Cases](#)**Search Results -**

Terms	Documents
18 same L11	27

**Database:**

US Patents Full-Text Database  
US Pre-Grant Publication Full-Text Database  
JPO Abstracts Database  
EPO Abstracts Database  
Derwent World Patents Index  
IBM Technical Disclosure Bulletins

**Search:**

L16

[Refine Search](#)[Recall Text](#)[Clear](#)**Search History****DATE:** **Thursday, June 27, 2002**   [Printable Copy](#)   [Create Case](#)

**Set Name Query**

side by side

**Hit Count Set Name**

result set

*DB=USPT; PLUR=YES; OP=ADJ*

<u>L16</u>	l8 same L11	27	<u>L16</u>
<u>L15</u>	l8 same L14	0	<u>L15</u>
<u>L14</u>	L11 same l13	2316	<u>L14</u>
<u>L13</u>	HPLC	43428	<u>L13</u>
<u>L12</u>	L11 or L10	62914	<u>L12</u>
<u>L11</u>	L10 or L9	62914	<u>L11</u>
<u>L10</u>	DMSO	39137	<u>L10</u>
<u>L9</u>	dimethyl sulfoxide	35776	<u>L9</u>
<u>L8</u>	L6 near8 L5	30336	<u>L8</u>
<u>L7</u>	l6 near8 L4	1380	<u>L7</u>
<u>L6</u>	remov\$4 or etch\$4	1618884	<u>L6</u>
<u>L5</u>	photoresist	48777	<u>L5</u>
<u>L4</u>	hard adj4 mask\$4	2285	<u>L4</u>
<u>L3</u>	low adj3 dielectric adj3 constant	7271	<u>L3</u>
<u>L2</u>	semiconduct\$4	253902	<u>L2</u>
<u>L1</u>	semiconduct\$4	253902	<u>L1</u>

END OF SEARCH HISTORY